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68POS. Memory Card Conne		DATE 5/12/09	
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1.0 OBJECTIVE

This specification covers the standard performance and evaluating conditions of 68Pos.Memory Card Connectors based on JEIDA IC Memory-Card Guidelines Ver. 4.1 and PCMCIA PC card Standard Release 2.0.

2.0 SCOPE

All products of and memory card connectors based on JEIDA Ver.4.1 and PCMCIA Release 2.0 shall conform to this specification.

3.0 **GENERAL**

This document is composed of the following sections:

<u>Paragraph</u>	<u>Title</u>
1.0	OBJECTIVE
2.0	SCOPE
3.0	GENERAL
4.0	REQUIREMENT
5.0	CONSTRUCTION
6.0	PERFORMANCE
7.0	TEST METHOD

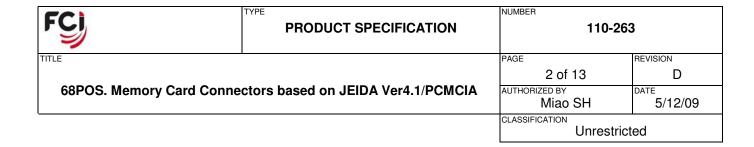
4.0 REQUIREMENT

4.1 Metallic components

1). Terminals	Beryllium copper with nickel underplating.				
(Socket Connector)	Contact area0.38 μ m or 0.75 μ m GXT.				
	Solder tailSolder plating of 2.5 μ m min. thick.				
	or Au Flash plating for "LF" suffix parts number.				
2). Terminals (Header)	Phosphor bronze with nickel underplating.				
	Contact areaOption 1: 0.38 μ m or 0.75 μ m GXT.				
	Option 2 : Gold plating of 0.25 μ m min thick.				
	Option 3: Gold Flash plating.				
	Solder tailSolder plating of 2.5 μ m min. thick.				
	or Sn plating 2.5 μ m min. thick.				
	or Au Flash plating.				

4.2 Plastic components

- 1). Socket housing --- Glass filled 66-Nylon or Glass filled PPS or Glass filled LCP. UL94V-0.
- 2). Header housing --- Glass filled 66-Nylon or Glass filled LCP.UL94V-0.



5.0 **CONSTRUCTION**

The connector consists of a socket connector and a header.

Attach a dummy card to the socket connector before inserting the socket connector into the header.

Fig. 5.1 shows a typical construction of the connector.

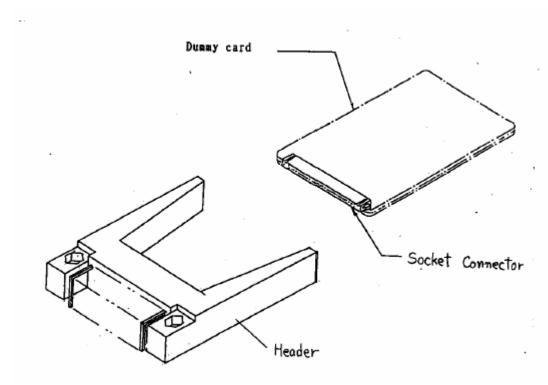
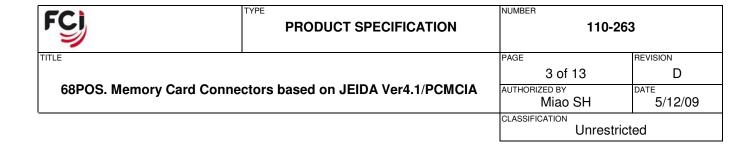


Fig. 5.1 Construction

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6.0 PERFORMANCE

Unless otherwise noted, the performance of connectors given in the attached list Shall satisfy the values specified in Table 5.1. The performance test shall follow the sequence given in Table 5.2. under the environmental condition(JIS C0010) listed below. All connectors to be tested shall be free of defects such as burr, flaw, void, chip, blister, pinhole, or sharp edge, which affect the life and Application of the connector.

Temperature ----15 – 35 $^{\circ}$ C Humidity ----25 – 85 $^{\circ}$

Pressure ----86 - 106 kPa(860 - 1060kPa)

6.1 performance

Table 6.1.Performance

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Item	Specification	rest method
Electrical:		
Rated current	Max. rated current - 0.5A.D.C (per pos.)	
Contact resistance	Initail - 40 m Ω max.	
(low level)	After the test - 20 m Ω max.change	7.1
	from the initial value	
Insulation resistance	Initail - 1,000 m Ω min.	7.2
	After the test - 100 M Ω min.	
Dielectric withstand-	No abnormality shall occur or leak current	
ing voltage	shall be 1 mA max. after applying AC 500 V	7.3
	for 1 min.	
Tem perature rise	30 ℃ max.(at rated current)	7.4
Environmental	After the test	
H u m idity	Insulation resistance - 100 M Ω min.	7.5
(steady state)	Contact resistance - 20 m Ω max.change	
	from the initial value	
Miosture resistance	After the test, the change in contact	
	resistance	
	shall be 20 m Ω max. from the initial.	7.6
Thermal shock	After the test, no evidence of crack, blister,	
	or rust which affect the funciton of connector.	7.7
	Insulation resistance - 100 M Ω min.	
	contact resistance - 20 m Ω max. change from	
	the initial value	

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	High temperature exposure	After the test, contact resistance shall be $20\ \text{m}\ \Omega$ max. change from the initial.	7.8
	Low temperature exposure	After the test, contact resistance shall be $20\ \text{m}\ \Omega$ max. change from the initial.	7.9
	Hydrogen sulfide (H2S)	After the test, contact resistance shall be $20\ m\ \Omega$ max. change from the initial.	7.10
	Salt spray	After the test, no evidence of crack, blister, or rust which affect the funciton of connector. 20 m Ω max. change from the initial in contact resistance	7.11
Mod	l hanical:	After the test, the change in contact	1.11
Mec	Durability (office environment)	resistance shall be $20 \text{ m} \Omega$ max. from the initial.	7.12
	Durability (harsh environment)	After the test, the change in contact resistance shall be $20 \text{ m} \Omega$ max. from the initial.	7.13
	Vibration	After the test, no looseness nor damage of the mated parts shall be found. During the test, no discontinuity over 100 n sec. Shall occur.	7.14
	Shock	The change in contact resistance shall be $20 \text{ m} \Omega$ max. from the initial.	7.15
	Total mating force Total unmating force	4 kg MAX. / 0.68kg MIN 4 kg MAX. / 0.68kg MIN	7.16
	Terminal withdrawal	10 g min. per position withdrawal force. (at initial)	7.17
	Terminal retention force	1.0 kg min.per header pin. 0.5 kg min.per socket terminal.	7.18
	Solderability	bath shall be wet with solder.	7.19
	Solder-heat resistance	No evidence of crack or warp which affect connector function.	7.20

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6.2 Test sequence

Table 6.2 Test sequence

Test Item									7	est	Gı	quo					-				
		1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20
Contact resistance (low level)	5. 1				99	⊕⊛	99	969	99	99	99	99	99	99	99						
Insulation resistance	6. 2	90	90													T	1-			\vdash	T
Dielectric with- standing voltage	6. 3	9	99															Τ		Γ	
Temp. rise	6. 4			Φ																	
Humidity	6. 5	3			2																
Moisture resistance	8. 6					2					.										
Termal shock	6. 7		3				2														
High temperature	6. 8							2										-			
Low temperature	6. 9								69												
Hydrogen sulfide	6. 10									9											
Salt spray	6. 11										69										
Durability (Office environment)	6. 12											0									
Durability (Harsh environment)	6. 13												0								
Vibration	6. 14													Ø							
Shock	6. 15										\neg				0					-,,	
Total mating/ unmating force	6. 16															Θ					
Terminal with- drawal force	6. 17				,												Θ			•	
Teremerou torce	6. 18																	Φ			
Socket terminal retention force	6. 18																		Φ		-
	5. 19																			0	
Solder-heat resistance	6. 20									\neg	\exists		\dashv	\neg	\neg						Φ

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7.0 TEST METHOD

7.1 Contact resistance (low level)

Contact resistance (low level) of mated connector shall be determined in Accordance with Test Method 3002 of MIL-STD-1344. The measure value indicates The electric resistance of the contact area and the bulk of two (header and socket) terminals as illustrated in Fig. 6.1

1). Test conditions

Test current : DC 1 mA max. Open Circuit voltage: DC 20 mA max

7.2 Insulation resistance

insulation resistance of mated connector shall be determined in accordance with Test Method 302 of MIL-STD-202.

1). Test conditions

Applied voltage: DC500 V Duration :1 minute

2). Measuring position

between adjacent terminals of the mated connector

7.3 Dielectric withstanding voltage

Dielectric withstanding voltage of the mated connector shall be determined in accordance with Test Method 301 of MIL-STD-202.

1). Test conditions

Applied voltage: AC 500V rms Duration : 1 minute

2). Measuring position

Between adjacent terminals of the mated connector.

7.4 Temperature rise

Temperature rise of the area adjacent to the contact point shall be Determined while carrying the test current through the mated connector.

1). Test conditions

test current: DC 0.5 A

2). Measuring method

Thermocouples or equivalent shall be used.

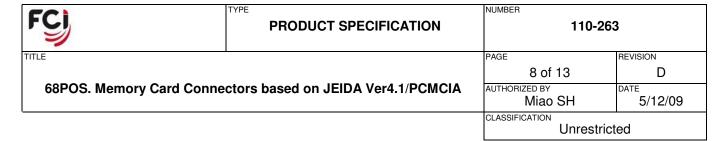
7.5 Humidity(steady state)

Humidity test of the mated connector shall be carried out in accordance with Test Method 103-B of MIL-STD-202. The measurement shall be done after allowing the connector to stand under the following conditions.

1). Test conditions

Temperature : $+40 \pm 2 \,^{\circ}\text{C}$ Humidity : $90 - 95 \,^{\circ}\text{RH}$ Duration : $96 \,^{\circ}\text{hrs}$

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7.6 Moisture Resistance

Moisture resistance shall be carried out in accordance with Test Method 106 of MIL-STD-202. The measurement shall be done after allowing the connector to stand under the following conditions.

1). Test conditions

Temperature : See Fig. 6.2 Humidity : See Fig. 6.2 Number of cycles : 10cycles

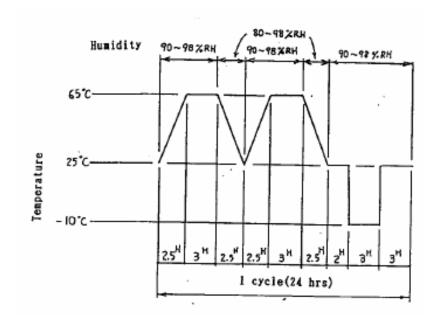


Fig. 7.2 Temperature – Humidity cycle of Moisture Resistance Test

7.7 Thermal shock

Thermal shock shall be carried out in accordance with Test Method 107 of MID-STD-202. After allowing the connector to stand under the following conditions, visual inspection shall be done to check for the absence of crack, crazing, or mechanical defect. After the visual inspection, the specified measurement Shall be conducted.

1). Test conditions

5 cycles (1 hr / cycle) Temperature : -55 $^{\circ}$ C - +85 $^{\circ}$ C

7.8 High temperature exposure

High temperature exposure shall be carried out in accordance with Test Method 108 of MIL-STD-202. The measurement shall be done after allowing the connector to stand under the following conditions.

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1). Test conditions

Temperature: $+85^{\circ}$ C Duration : 250 hrs

7.9 Low temperature exposure

Low temperature exposure shall be carried out in accordance with JIS C 0020. The measurement shall be done after allowing the connector to stand under the following conditions.

1). Test conditions

Temperature: -55° C Duration : 96 hrs

7.10 Hydrogen sulfide (H2S) exposure

Hydrogen sulfide exposure of the mated connector shall be carried out in Accordance with JEIDA-38. The measurement shall be done after allowing the connector to stand under the following conditions.

1). Test conditions

Hydrogen sulfide concentration: 3 ppm

Temperature : $40 \,^{\circ}\text{C}$ Humidity : $80\% \, \text{PH}$ Duration : $96 \, \text{hrs}$

7.11 Salt spray

Salt Spray shall be carried out in accordance with Test Method 101 of MIL-STD-202. The measurement shall be done after allowing the connector to stand under the following conditions, lightly washing it with water, then drying it for 24 hours.

1). Test conditions

Salt concentration: 5 % Temperature : +35 °C Duration : 48 hrs

7.12 Durability(office environment)

Measurement shall be done before and after the socket connector and header are mated and unmated at the rate of 400 - 2600 cycles / hr.

1). Test conditions

Number of insertion / withdrawal: 10 000 cycles Temperature : 15-35 $^{\circ}$ C Humidity : 25-85 $^{\circ}$ PH

7.13 Durability (harsh environment)

Measurement shall be done before and after the following test sequence.

1). Test sequence

Insertion / withdrawal 1,000 cycles *1

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↓
Moisture resistance 1 cycle *2
↓
Insertion / withdrawal 1,000 cycles (Total 2000 cycles) *1
↓
Moisture resistance 1 cycle (Total 2000 cycles) *2
↓
Insertion / withdrawal 3,000 cycles (Total 5000 cycles) *1
↓
Moisture resistance 1 cycle (Total 3 cycles) *2
↓
Hydrogen sulfide exposure 96hrs *3

*1 : Insertion / Withdrawal speed : $400{\sim}600$ cycles / hr.

*2 : See Test Method 6.6

*3: See Test Method 6.10

7.14 Vibration

Mount the connector onto the test table as shown in Fig.6.3, and apply Vibration to the table under the following conditions. The test shall be In accordance with Test Method 204 of MIL-STD-202.

- 1). Test conditions: \pm 15G. 10 2000 Hz
- 2). Duration: 4 hrs, for each axial direction of 3 dimensions (total 12 hrs)

7.15 Shock

Mount the connector onto the test table as shown in fig.6.3. , and apply vibration to the table under the following conditions. The test shall be In accordance with Test 213 of MIL-STD-202.

- 1). Test conditions: 50G 11ms half wave of sine wave
- 2). Number of shocks : 3 shocks in every axial direction of 3 dimensions (total 18 shocks)

7.16 Total mating / unmating force

Determine the maximum load necessary to mate the socket connector with the Header along the axial direction. Also determine the maximum load to unmate the two in the same way.

1). Test conditions

Speed of insertion / withdrawal : 25 mm / min

7.17 Terminal withdrawal force

Maximum load to withdraw the specified gage pin along the axial direction Shall be measured.

1). Test conditions

Withdrawal speed: 25 mm / min

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Pin diameter : $\Phi\,0.42\pm0.052$ made of tool steel (HRC=50-55)

7.18 Terminal retention force

Terminal retention force shall be determined for both the socket connector and header. Care should be taken during the measurement to secure to secure the bodies of the socket connector and header housings, and to the direction of terminal withdrawal. Cross-head speed shall be kept at 25 mm / min.

1). Terminal retention force of the socket connector

When a terminal within the housing is withdrawn along the axial direction While securing the socket housing with a fixture, the values specified In Table 5.1 shall be satisfied. (See Fig.6.4)

2). Terminal retention force of the header

When a terminal is withdrawn along the axial direction while securing the Header housing body with a fixture, the values specified in Table 5.1. Shall be satisfied. (See Fig.6.5)

7.19 Solderability

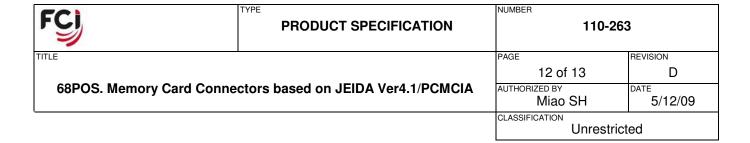
Conforming to Test Method 208 of MIL-STD-202, the solder tail (solder plated) of the header housing and socket housing shall be dipped into a flux (alpha 100, GX-5, GX-7), for 5 to 10 seconds, then they are dipped into a solder bath (Sn 60, Pb 40) at 230 \pm 5 $^{\circ}\mathrm{C}$ for 3 \pm 0.5 sec. or (Sn-Ag3.0-Cu0.5) at 260 \pm 5 $^{\circ}\mathrm{C}$ for 3 \pm 0.5 sec. (for lead free Product.) After the procedure, observe the Area covered with the solder.

7.20 Solder-heat resistance

Solder-heat resistance of the header and socket connector shall be in accordance With Test Method 210 of MIL-STD-202. Mount the header to the printed wiring board, And dip the tails projected from the bottom of the board and the solder tails of The socket connector into a solder bath at 260 \pm 5 °C for 10 \pm 1sec. Observe the condition of the header and socket housings.

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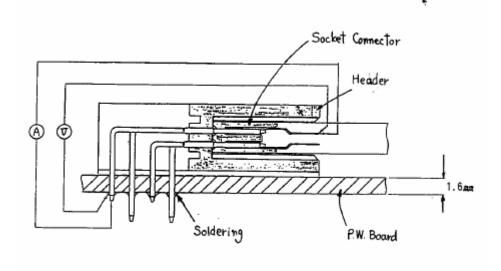


Fig. 6.1 Contact Resistance Measurement (Low Level)

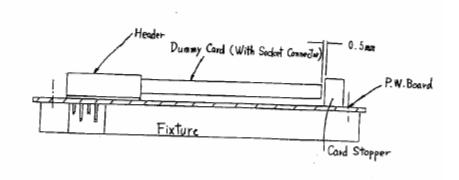
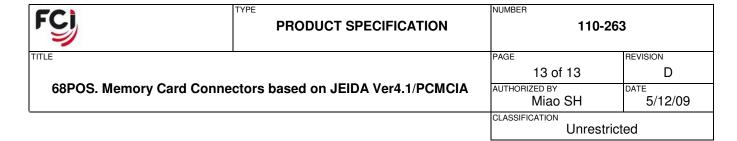


Fig. 6.3 Shock and Vibration



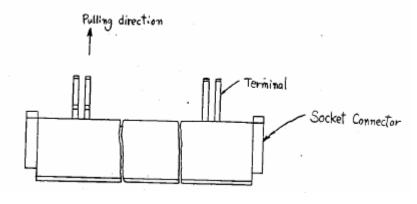


Fig. 6.4 Terminal Retention of Socket Connector

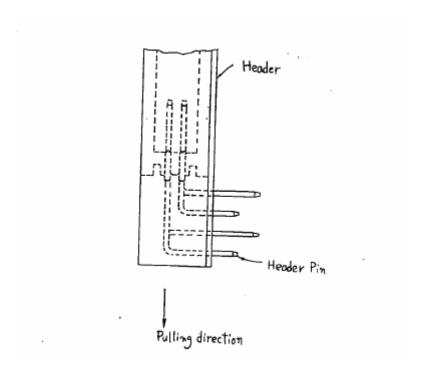


Fig. 6.5 Terminal Retention Force of header

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